

MT80-A0.4-2000

AO MODULATOR/SHIFTER



Product Overview

These free space modulators has been specially designed to work in the far infrared region, particularly in the wavelength range of 1950 nm to 2100 nm. Their carrier frequency of 80 MHz will enable a fix frequency shift of 80 MHz as well as a variable frequency shift of 80 +/- 15 MHz.

In addition, it can be used as intensity/ amplitude modulator with a rise time in the ns range

Features

- Small rise time
- Linear polarization
- High diffraction efficiency

Access to your operating manual



TECHNICAL DATA SHEET 2014

Technical Specifications

Parameter	MT80-A0.4-2000
Material-Acoustic mode-Velocity	Te02 [L] - 4200 m/s
Optical Wavelength range (AR coated)	1950 nm -2100 nm
Optical Transmission	> 95 %
Input / Output Polarization	Linear / Linear
Active Aperture	0.4 x 2 mm ²
Carrier Frequency / Frequency shift	+/- 80 MHz
Separation Angle (0-1)	38 mrad @ 2000 nm
Static Extinction Ratio	> 33 dB
Rise / Fall time	160 ns / mm
Diffraction Efficiency	> 65% nom 70% with TEM00 laser beam, M ² ≤1.1
Analog Amplitude modulation bandwidth (-3 dB)	12 MHz, with 0.3 mm beam diameter
Input impedance	Nom 50 Ω
Max optical power density (CW)	5 W/ mm ²
V.S.W.R.	Nom < 1.2/1
Size / Weight	(Lxhx) 50.9 x 22.4 x 17.3 / 50 g IN PRO 005
RF Power / Connector	≤ 2.2/ SMA
Operating Temperature	+10 to +40 Non condensing
Storage Temperature	-40 to +50 Non condensing

On request

VARIABLE FREQUENCY SHIFT

80 +/- 15 MHz

Diffraction Efficiency: >65%@ F0, >50% over range

Rise Time (T_r) is beam diameter (Φ) sensitive:

$$T_r = 0.66 \frac{\Phi}{V}$$

Amplitude modulation bandwidth (F_{-3dB}) is rise time (T_r) sensitive:

$$F_{-3dB} = \frac{0.48}{T_r}$$

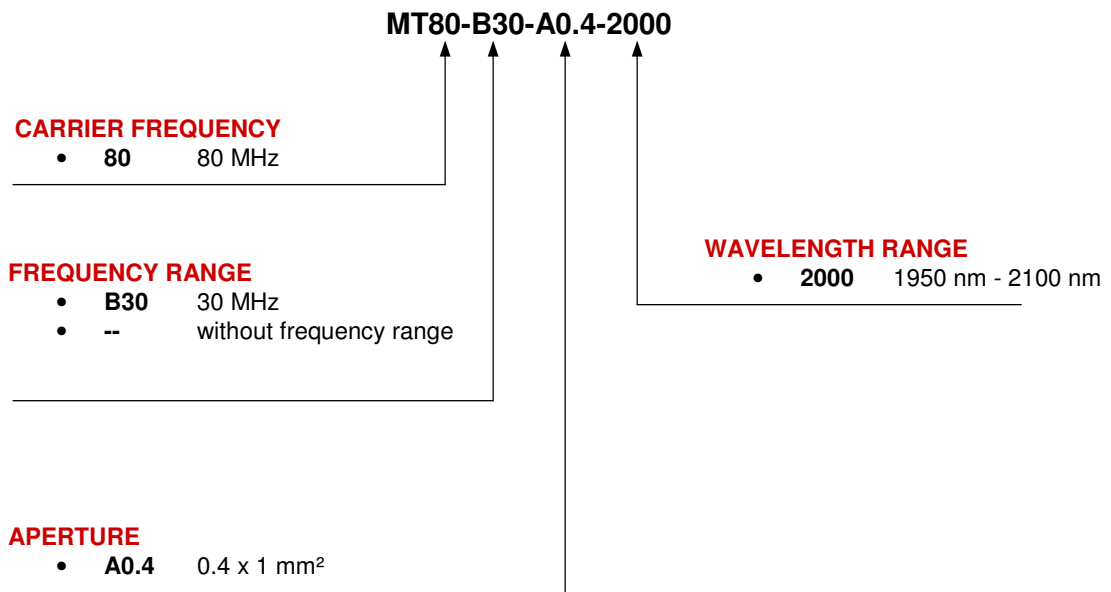
Separation angle ($\Delta\theta$) is wavelength (λ) sensitive:

$$\Delta\theta = \frac{\lambda F}{V}$$

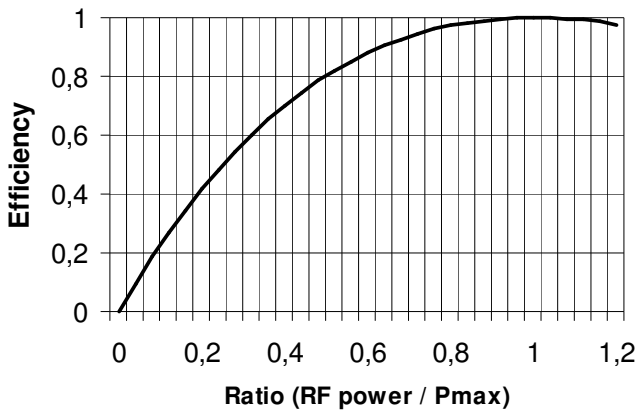
RF power (P) is wavelength (λ) sensitive:

$$\frac{P_1}{P_2} = \frac{\lambda_1^2}{\lambda_2^2}$$

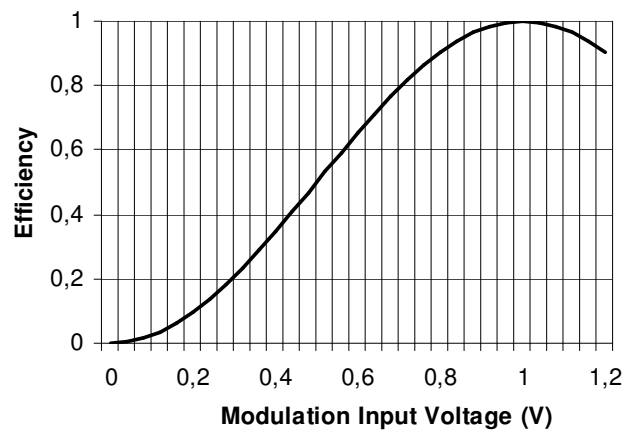
How to determine your model



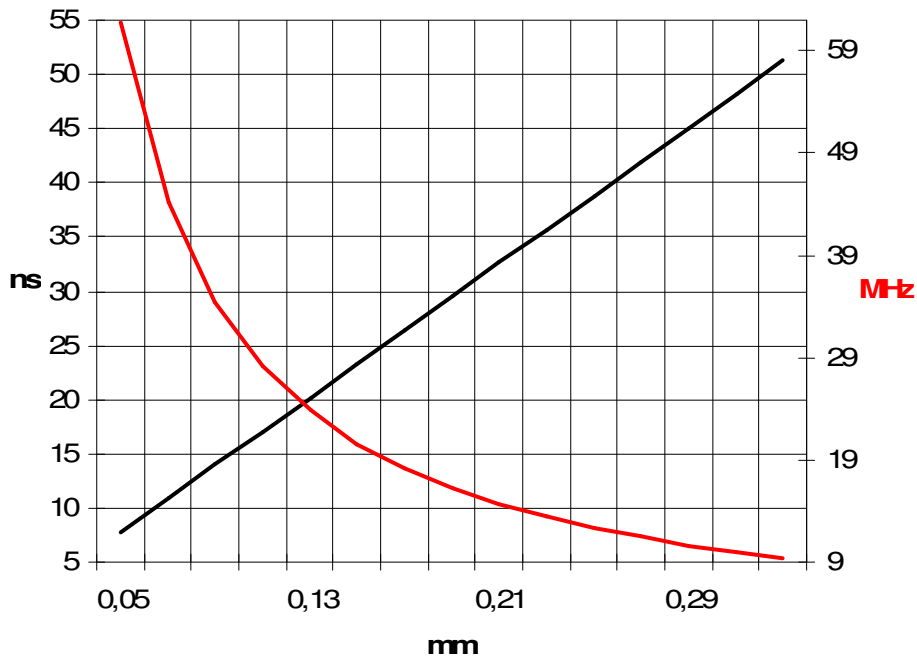
Relative Efficiency versus RF power



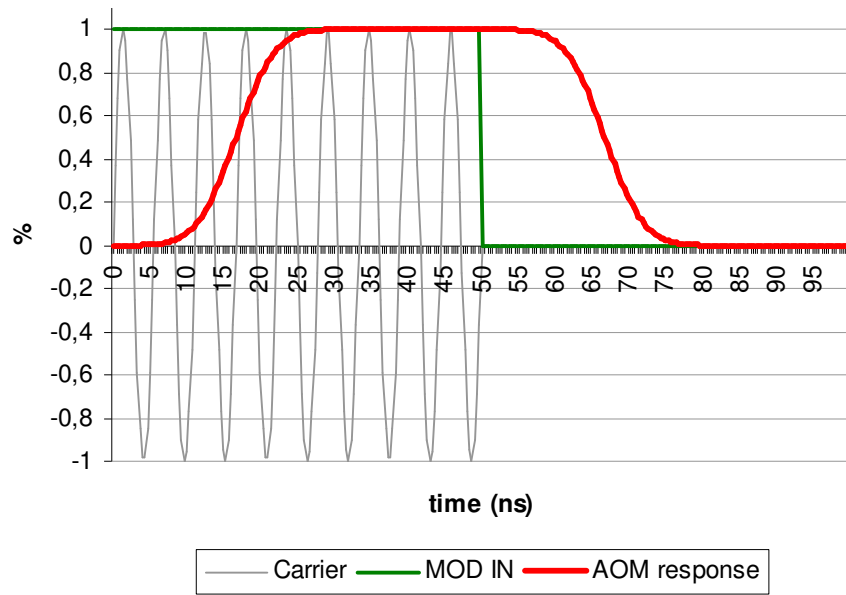
AO relative Efficiency vs driver MOD IN



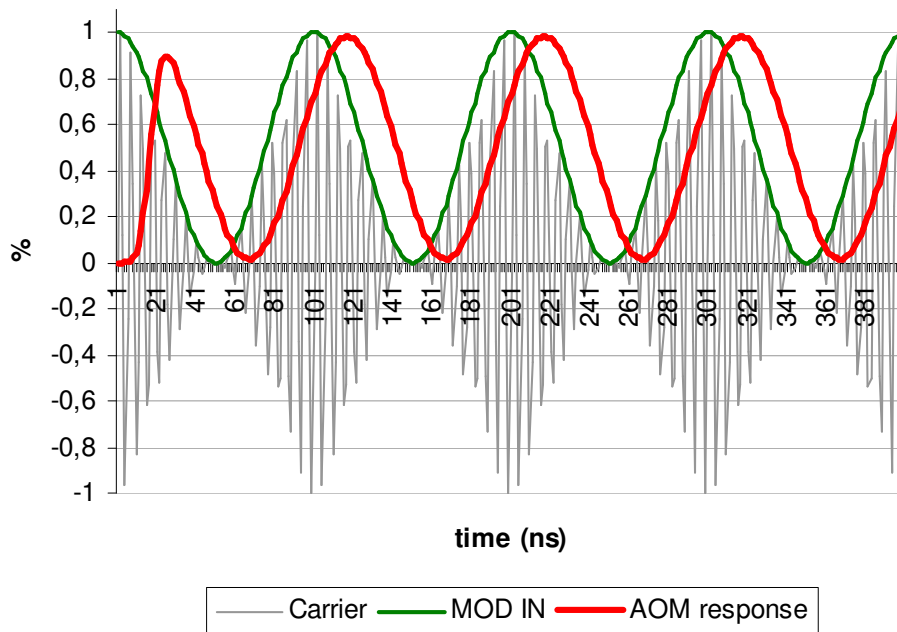
Rise Time (black) / Analog Modulation BW (-3dB) vs Beam diameter

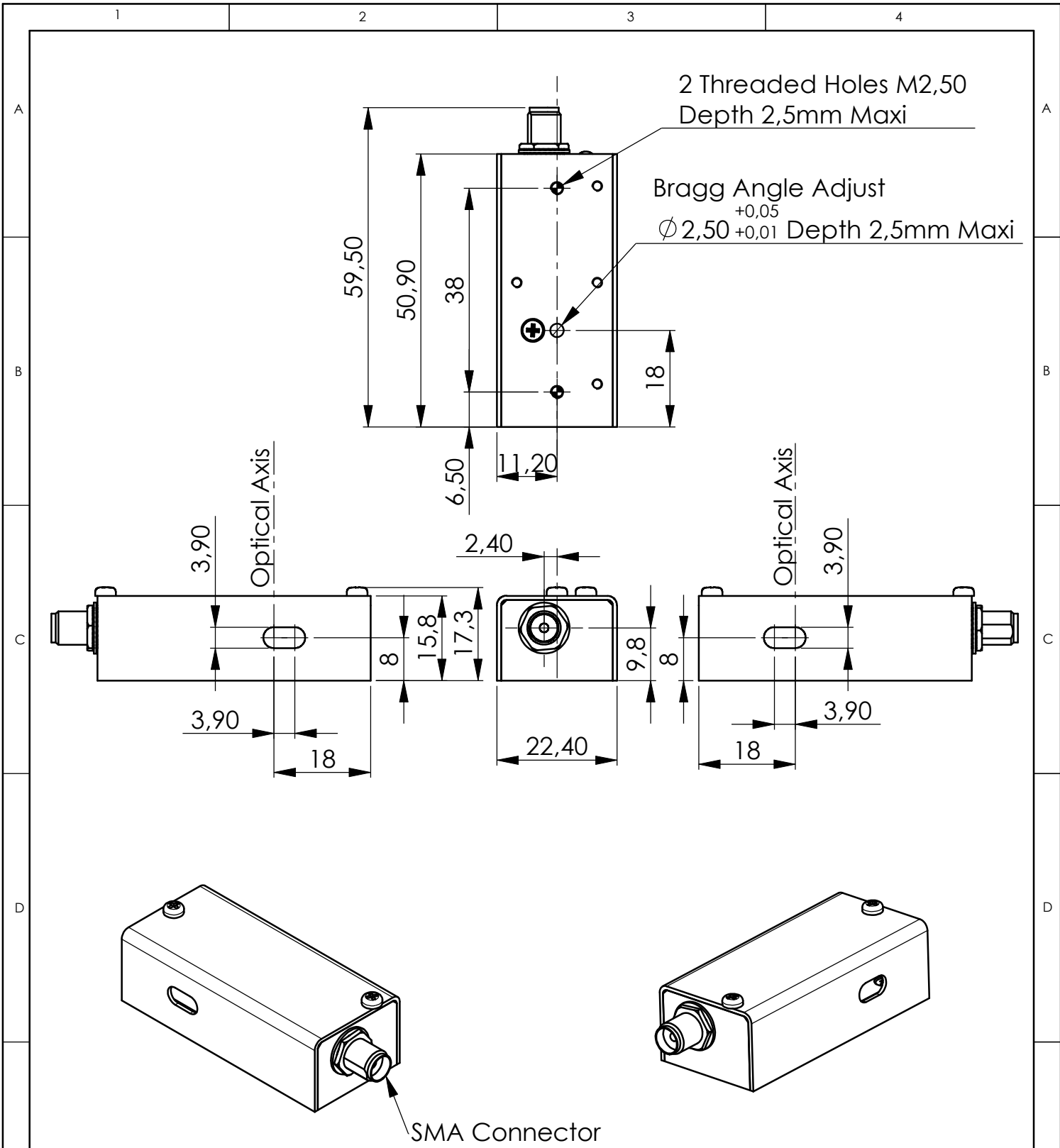


Relative Efficiency / AOM temporal response



Relative Efficiency / AOM temporal response (10MHz)





B	18/12/06	E.D	Reprise mise en plan
A	15/10/03	F.C	Plan initial / Initial Drawing
Index	Date	Auteur Author	Modifications
Conception Design	E.D	PLAN D'INTERFACE / OUTLINE DRAWING	
Vérification Checking	L.F		
Tolérance Tolerance	ISO 2768mK	Référence / Reference	
Echelle Scale	1:1	IN-PRO-005	
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